VT-706

Temperature Compensated Crystal Oscillator

Description

Vectron's VT-706 Temperature Compensated Crystal Oscillator (TCXO) is a quartz stabilized, Clipped sine wave or CMOS output, analog temperature compensated oscillator, operating off a 5.0 or 3.3 volt supply in a hermetically sealed 7.0 x 5.0 mm ceramic package.

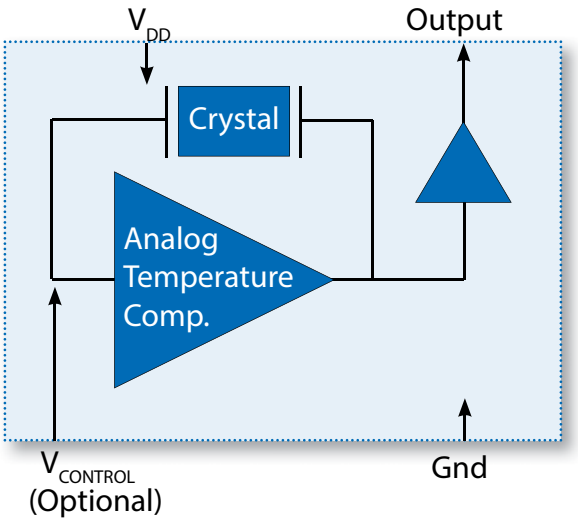
Features

- 5.000 - 52.000MHz Output Frequency
- ±0.2ppm Temperature Stability
- Optional Frequency Tuning
- Fundamental Crystal Design
- Stratum 3 version available as a custom part number
- Gold over nickel contact pads
- Hermetically Sealed Ceramic SMD package
- Product is compliant to RoHS directive and fully compatible with lead free assembly

Applications

- Femto Cells
- Base Stations
- IP Networking
- Global Positioning Systems
- Point to Point Radio
- Manpack Radio
- Test and Measurement

Block Diagram



Specifications

Table 1. Electrical Performance, Clipped Sine Wave Option					
Parameter	Symbol	Min.	Typ	Max	Units
Output Frequency[1], *Ordering Option*	f_O	5		52	MHz
Supply Voltage[3], *Ordering Option*	V_{DD}	+2.8, +3.0, +3.3, +5.0			V
Supply Current	I_{DD}			3.5	mA
Operating Temperature, *Ordering Option*	T_{OP}	0/55, -10/70, -20/70, -30/80, -30/85, -40/85			°C
Frequency Stability					
Stability Over T_{OP}[4], *Ordering Option*	F_{STAB}	±0.05, ±0.10, ±0.20, ±0.28, ±0.50			ppm
Frequency Tolerance[5]	F_{TOL}			±2.0	ppm
Power Supply Stability, ±5%	F_{PWR}			±0.1	ppm
Load Stability, ±10%	F_{LOAD}			±0.05	ppm
Aging / 1st year	F_{AGE}			±1.0	ppm
Frequency Tuning (EFC), *Ordering Option*					
Tuning Range[6]	PR	±5.0, ±8.0, ±10.0, ±12.0			ppm
Tuning Slope		Positive			
Control Voltage to reach Pull Range	V_C	0.5	1.5	2.5	V
Control Voltage Impedance		100			Kohm
RF Output (Clipped Sine Wave), *Ordering Option*					
Output Level High	V_O p-p	0.8			V
Output Load	C_L		10k || 10pF		
Start Up Time	t_{SU}			2	ms
Phase Noise[7]					
Phase Noise, 10.00MHz[7]	$Ø_N$				dBc/Hz
10Hz			-99		
100Hz			-126		
1kHz			-145		
10kHz			-152		
100kHz			-155		

1. Refer to Table 8 for Standard Frequencies. Other Frequencies are available on request. Check with factory.
2. Output DC-cut capacitor is optional.
3. The VT-706 power supply pin (Pin4) should be filtered using a by-pass capacitor of 0.1uF for optimal performance.
4. Referenced to the midpoint between minimum and maximum frequency value over Operating Temperature Range.
5. Frequency measured at 25 °C, 1 hour after 2 IR reflows.
6. Referenced to Mid Control Voltage
7. Measured at ambient temperature using Agilent E5052B Signal Source Analyzer.

Table 2. Electrical Performance, CMOS Option					
Parameter	Symbol	Min.	Typ	Max	Units
Output Frequency[1], *Ordering Option*	f_O	5		52	MHz
Supply Voltage[3], *Ordering Option*	V_{DD}	+2.8, +3.0, +3.3, +5.0			V
Supply Current	I_{DD}			6.0	mA
Operating Temperature, *Ordering Option*	T_{OP}	0/55, -10/70, -20/70, -30/80, -30/85, -40/85			°C
Frequency Stability					
Stability Over T_{OP}[4], *Ordering Option*	F_{STAB}	±0.05, ±0.10, ±0.20, ±0.28, ±0.50			ppm
Frequency Tolerance[5]	F_{TOL}			±2.0	ppm
Power Supply Stability, ±5%	F_{PWR}			±0.1	ppm
Load Stability, ±10%	F_{LOAD}			±0.05	ppm
Aging / 1st year	F_{AGE}			±1.0	ppm
Frequency Tuning (EFC), *Ordering Option*					
Tuning Range[6]	PR	±5.0, ±8.0, ±10.0, ±12.0			ppm
Tuning Slope		Positive			
Control Voltage to reach Pull Range	V_C	0.5	1.5	2.5	V
Control Voltage Impedance		100			Kohm
RF Output (CMOS), *Ordering Option*					
Output Level High Output Level Low	V_{OH} V_{OL}	0.9*V_{DD}		 0.1*V_{DD}	V
Output Load	C_L			15	pF
Duty Cycle		45		55	%
Start Up Time	t_{SU}			2	ms
Rise & Fall Times				4	ns
Phase Noise[7]					
Phase Noise, 10.00MHz[7] 10Hz 100Hz 1kHz 10kHz 100kHz	$\emptyset_N$		 -102 -128 -147 -154 -156		dBc/Hz

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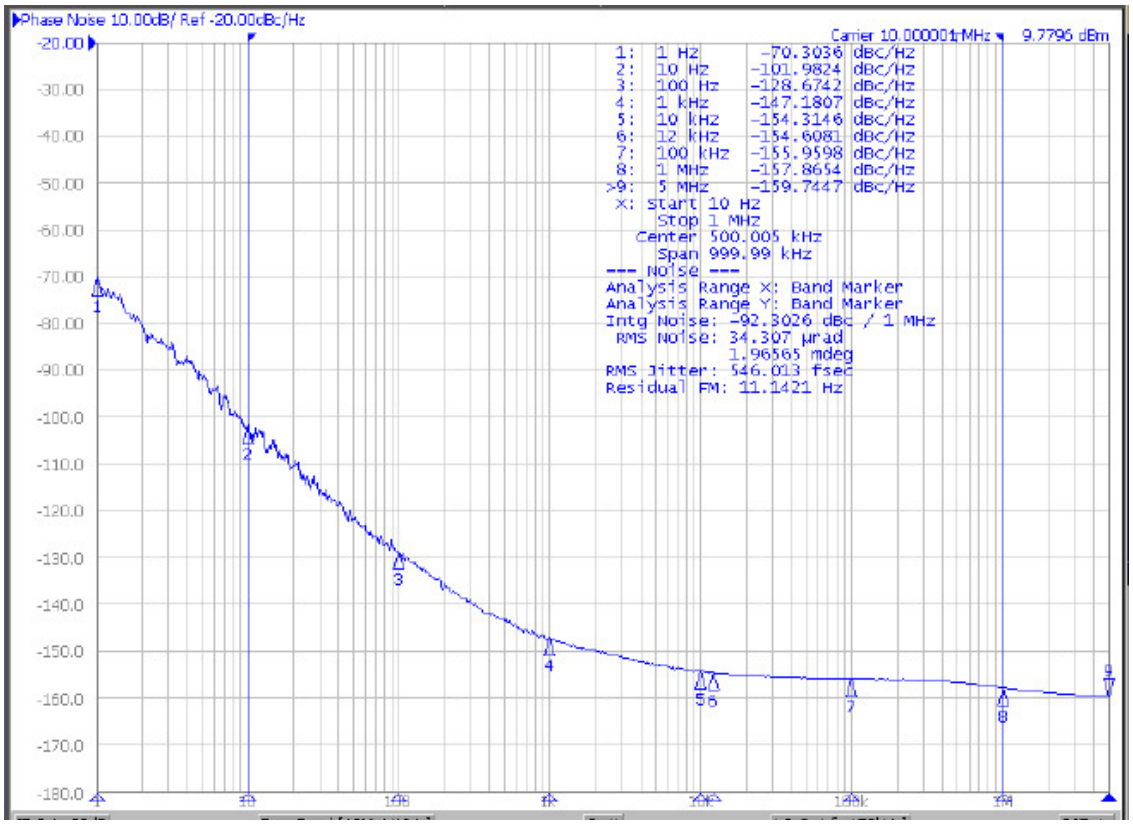
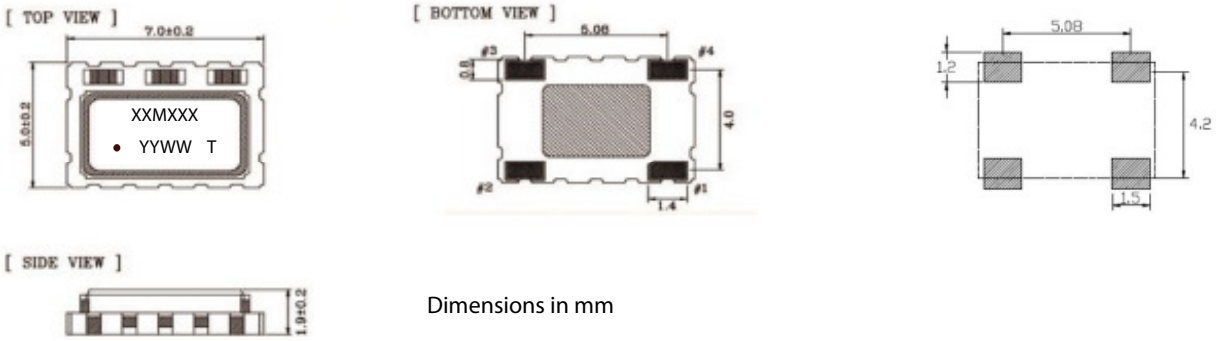
Phase Noise Performance for 10MHz CMOS



Package Outline Drawing & Pad Layout



Dimensions in mm

Marking Information

XXMXX - Frequency (Example: 10M000)

YY - Year of Manufacture

WW - Week of the Year

T - Manufacturing Location

• - Pin 1 Indicator

Table 3. Pinout

Pin #	Symbol	Function
1	Vc or NC	TCXO Control Voltage or No Connect
2	GND	Ground
3	OUT	RF Output
4	V_{DD}	Supply Voltage

Note:

0.1uF capacitor is a by-pass power supply filter capacitor placed between Pin4 (Vdd) and Ground for optimal performance.

Maximum Ratings

Absolute Maximum Ratings and Handling Precautions

Stresses in excess of the absolute maximum ratings can permanently damage the device. Functional operation is not implied or any other excess of conditions represented in the operational sections of this data sheet. Exposure to absolute maximum ratings for extended periods may adversely affect device reliability.

Although ESD protection circuitry has been designed into the VT-706, proper precautions should be taken when handling and mounting, VI employs a Human Body Model and Charged Device Model for ESD susceptibility testing and design evaluation.
ESD thresholds are dependent on the circuit parameters used to define the model. Although no industry standard has been adopted for the CDM a standard resistance of 1.5kOhms and capacitance of 100pF is widely used and therefor can be used for comparison purposes.

Table 4. Maximum Ratings			
Parameter	Symbol	Rating	Unit
Storage Temperature	T_{STORE}	-55/125	°C
Supply Voltage	V_{DD}	-0.6/6	V
Control Voltage	V_C	-0.6/V_{DD}+0.6	V
Enable/Disable Voltage	E/D	-0.6/V_{DD}+0.6	V
ESD, Human Body Model		1500	V
ESD, Charged Device Model		1000	V

Reliability

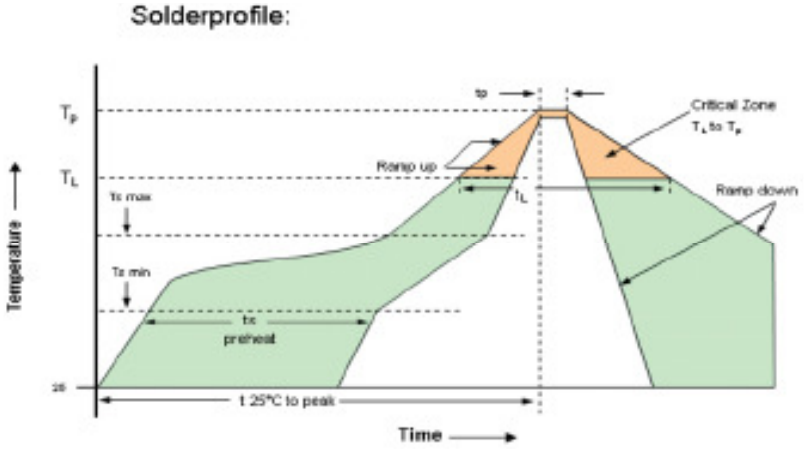
Table 5. Environmental Compliance	
Parameter	Condition
Mechanical Shock	MIL-STD-883 Method 2002
Mechanical Vibration	MIL-STD-883 Method 2007
Temperature Cycle	MIL-STD-883 Method 1010
Solderability	MIL-STD-883 Method 2003
Fine and Gross Leak	MIL-STD-883 Method 1014
Resistance to Solvents	MIL-STD-883 Method 2015
Moisture Sensitivity Level	MSL1
Contact Pads	Gold over Nickel

IR Reflow

Suggested IR Profile

Devices are built using lead free epoxy and can be subjected to standard lead free IR reflow conditions shown in Table 6. Contact pads are gold over nickel and lower maximum temperatures can also be used, such as 220°C.

Table 6. Reflow Profile		
Parameter	Symbol	Value
PreHeat Time Ts-min Ts-max	t_s	200 sec Max 150°C 200°C
Ramp Up	R_{UP}	3°C/sec Max
Time above 217C	t_L	150 sec Max
Time to Peak Temperature	$t_{25C\ to\ peak}$	480 sec Max
Time at 260C	t_P	30 sec Max
Time at 240C	t_{P2}	60 sec Max
Ramp down	R_{DN}	6°C/sec Max



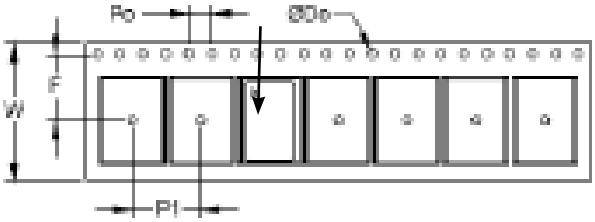
VCXO Function

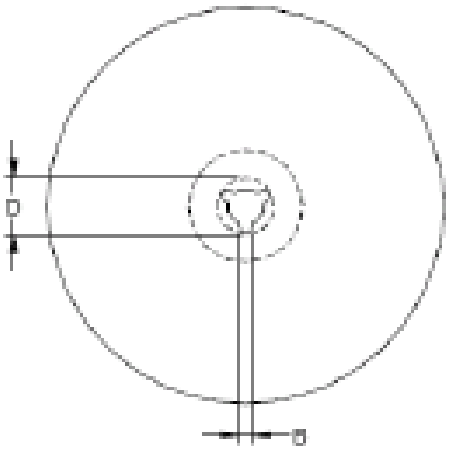
VCXO Feature: The VT-706 is supplied with a VCXO function for applications were it will be used in a PLL, or the output frequency needs fine tune or calibration adjustments. This is a high impedance input, 100kOhm, and can be driven with an op-amp or terminated with adjustable resistors etc. **Pin1 should not be left floating on the VCXO optional device.**

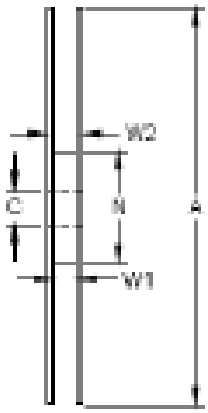
Tape & Reel

Table 7. Tape and Reel Information

Tape Dimensions (mm)					Reel Dimensions (mm)							
W	F	Do	Po	P1	A	B	C	D	N	W1	W2	#/Reel
16	7.5	1.5	4	8	180	1.5	13	20.2	60	16.4	20.4	1000







Ordering Information

VT-706- E F W - 207A- xxMxxxxxxx

Product
TCXO

Package
7.0 x 5.0 Package

Voltage Options
D: +5.0 Vdc ± 5%
E: +3.3 Vdc ± 5%
F: +3.0Vdc ± 5%
G: +2.8Vdc ± 5%

Output
A: CMOS
F: Clipped Sine Wave

Temp Range
R: 0/55°C
W: -10/70°C
J: -20/70°C
G: -30/80°C
H: -30/85°C
E: -40/85°C

Frequency in MHz

Tuning
0: Fixed, No tuning
A: ±5ppm
B: ±8ppm
C: ±10ppm
D: ±12ppm

Stability
508: ±0.05ppm
107: ±0.10ppm
207: ±0.20ppm
287: ±0.28ppm
507: ±0.50ppm

**Note: not all combination of options are available.*
Other specifications may be available upon request.

Example: VT-706-EFW-207A-19M2000000

* Add **_SNPBDIP** for tin lead solder dip
Example: VT-706-EFW-207A-19M20000000_SNPBDIP

Standard Frequencies & Capability Chart

Table 8. Standard Frequencies (MHz)

10.000	12.800	16.384	19.200	19.440	20.000	25.000	26.000	40.000	50.000

Note: Other Frequencies are available on request.

Table 9. Capability Chart [Clipped Sine & CMOS Output]

	±0.05ppm	±0.10ppm	±0.20ppm	±0.28ppm	±0.50ppm
0/55°C	●	●	●	●	●
-10/70°C	●	●	●	●	●
-20/70°C	●	●	●	●	●
-30/85°C	●	●	●	●	●
-40/85°C	●	●	●	●	●

● = Can be provided.
● = Under development. Please consult with factory.
● = Cannot be provided.

Revision History

Revision Date	Approved	Description
Sept 10, 2015	VN	Rev 0.0: VT-706 Preliminary Datasheet - Internal Verification (Factory Approval)
Sept 17, 2015	VN	Rev 0.1: VT-706 Preliminary Datasheet for Product Launch.
Sept 19, 2016	VN	Rev 0.2: Removed "Preliminary" from datasheet
Aug 10, 2018	FB	Rev 0.3: Updated logo and contact information, added "SNPBDIP" ordering option

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